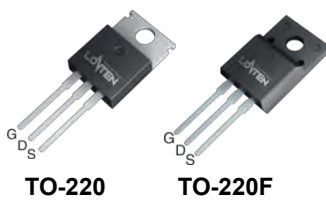
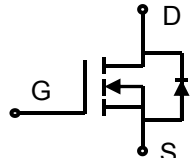


Lonten N-channel 500V, 13A Power MOSFET

| | | | | | | | | | |
|---|--|-----------|------|-------|-----|------------------|---------------|-------------|-------|
| <p>Description</p> <p>The Power MOSFET is fabricated using the advanced planar VDMOS technology. The resulting device has low conduction resistance, superior switching performance and high avalanche energy.</p> <p>Features</p> <ul style="list-style-type: none"> ◆ Low $R_{DS(on)}$ ◆ Low gate charge (typ. $Q_g = 33$ nC) ◆ 100% UIS tested ◆ RoHS compliant <p>Applications</p> <ul style="list-style-type: none"> ◆ Electronic ballast ◆ Switched mode power supplies. ◆ UPS. | <p>Product Summary</p> <table> <tr> <td>V_{DSS}</td> <td>500V</td> </tr> <tr> <td>I_D</td> <td>13A</td> </tr> <tr> <td>$R_{DS(on),max}$</td> <td>0.46Ω</td> </tr> <tr> <td>$Q_{g,typ}$</td> <td>33 nC</td> </tr> </table> <div style="text-align: center;">  <p>TO-220 TO-220F</p>  <p>N-Channel MOSFET</p> </div> | V_{DSS} | 500V | I_D | 13A | $R_{DS(on),max}$ | 0.46 Ω | $Q_{g,typ}$ | 33 nC |
| V_{DSS} | 500V | | | | | | | | |
| I_D | 13A | | | | | | | | |
| $R_{DS(on),max}$ | 0.46 Ω | | | | | | | | |
| $Q_{g,typ}$ | 33 nC | | | | | | | | |

Absolute Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|----------------|-------------|---------------------|
| Drain-Source Voltage | V_{DSS} | 500 | V |
| Continuous drain current ($T_C = 25^\circ\text{C}$) | I_D | 13 | A |
| ($T_C = 100^\circ\text{C}$) | | 8 | A |
| Pulsed drain current ¹⁾ | I_{DM} | 52 | A |
| Gate-Source voltage | V_{GSS} | ± 30 | V |
| Avalanche energy, single pulse ²⁾ | E_{AS} | 845 | mJ |
| Peak diode recovery dv/dt ³⁾ | dv/dt | 5 | V/ns |
| Power Dissipation TO-220F ($T_C = 25^\circ\text{C}$) | P_D | 50 | W |
| Derate above 25°C | | 0.4 | W/ $^\circ\text{C}$ |
| Power Dissipation TO-220 ($T_C = 25^\circ\text{C}$) | | 212 | W |
| Derate above 25°C | | 1.69 | W/ $^\circ\text{C}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |
| Continuous diode forward current | I_S | 13 | A |
| Diode pulse current | $I_{S,pulse}$ | 52 | A |

Thermal Characteristics

| Parameter | Symbol | Value | | Unit |
|---|-----------------|---------|--------|---------------------------|
| | | TO-220F | TO-220 | |
| Thermal resistance, Junction-to-case | $R_{\theta JC}$ | 2.5 | 0.59 | $^\circ\text{C}/\text{W}$ |
| Thermal resistance, Junction-to-ambient | $R_{\theta JA}$ | 62.5 | 62.5 | $^\circ\text{C}/\text{W}$ |

Package Marking and Ordering Information

| Device | Device Package | Marking | Units/Tube | Units/Reel |
|----------|----------------|----------|------------|------------|
| LNC13N50 | TO-220 | LNC13N50 | 50 | |
| LND13N50 | TO-220F | LND13N50 | 50 | |

Electrical Characteristics

$T_c = 25^\circ\text{C}$ unless otherwise noted

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|--------------------------------------|---------------|--|------|------|----------|---------------|
| Static characteristics | | | | | | |
| Drain-source breakdown voltage | BV_{DSS} | $V_{GS}=0\text{ V}, I_D=0.25\text{ mA}$ | 500 | - | - | V |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=0.25\text{ mA}$ | 2 | - | 4 | V |
| Drain cut-off current | I_{DSS} | $V_{DS}=500\text{ V}, V_{GS}=0\text{ V},$ $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$ | - | - | 1 100 | μA |
| Gate leakage current, Forward | I_{GSSF} | $V_{GS}=30\text{ V}, V_{DS}=0\text{ V}$ | - | - | 100 | nA |
| Gate leakage current, Reverse | I_{GSSR} | $V_{GS}=-30\text{ V}, V_{DS}=0\text{ V}$ | - | - | -100 | nA |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}=10\text{ V}, I_D=6.5\text{ A}$ | - | 0.37 | 0.46 | Ω |
| Dynamic characteristics | | | | | | |
| Input capacitance | C_{iss} | $V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$ | - | 1960 | - | pF |
| Output capacitance | C_{oss} | | - | 185 | - | |
| Reverse transfer capacitance | C_{rss} | | - | 3 | - | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD} = 250\text{ V}, I_D = 13\text{ A}$ $R_G = 10\ \Omega, V_{GS}=15\text{ V}$ | - | 13 | - | ns |
| Rise time | t_r | | - | 36 | - | |
| Turn-off delay time | $t_{d(off)}$ | | - | 62 | - | |
| Fall time | t_f | | - | 13 | - | |
| Gate charge characteristics | | | | | | |
| Gate to source charge | Q_{gs} | $V_{DD}=400\text{ V}, I_D=13\text{ A},$ $V_{GS}=0\text{ to }10\text{ V}$ | - | 8.5 | - | nC |
| Gate to drain charge | Q_{gd} | | - | 10.3 | - | |
| Gate charge total | Q_g | | - | 33 | - | |
| Gate plateau voltage | $V_{plateau}$ | | - | 5 | - | V |
| Reverse diode characteristics | | | | | | |
| Diode forward voltage | V_{SD} | $V_{GS}=0\text{ V}, I_F=13\text{ A}$ | - | - | 1.3 | V |
| Reverse recovery time | t_{rr} | $V_R=250\text{ V}, I_F=13\text{ A},$ $di_F/dt=100\text{ A}/\mu\text{s}$ | - | 305 | - | ns |
| Reverse recovery charge | Q_{rr} | | - | 3.4 | - | μC |
| Peak reverse recovery current | I_{rrm} | | - | 22 | - | A |

Notes:

- Pulse width limited by maximum junction temperature.
- $L=10\text{mH}, I_{AS} = 13\text{A}$, Starting $T_j = 25^\circ\text{C}$.
- $I_{SD} = 13\text{A}, di/dt \leq 100\text{A}/\mu\text{s}, V_{DD} \leq BV_{DS}$, Starting $T_j = 25^\circ\text{C}$.

Electrical Characteristics Diagrams

Figure 1. Typical Output Characteristics

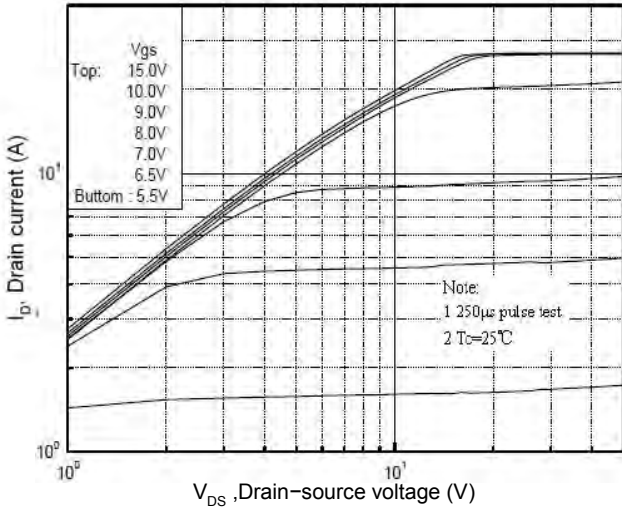


Figure 3. On-Resistance Variation vs. Drain Current

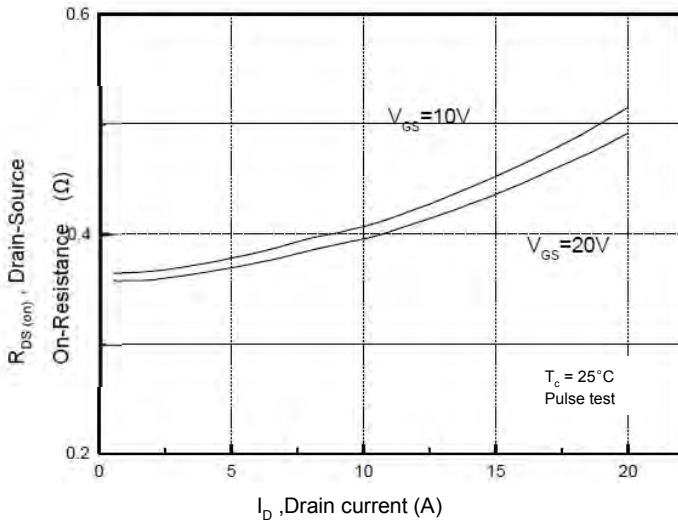


Figure 5. Breakdown Voltage vs. Temperature

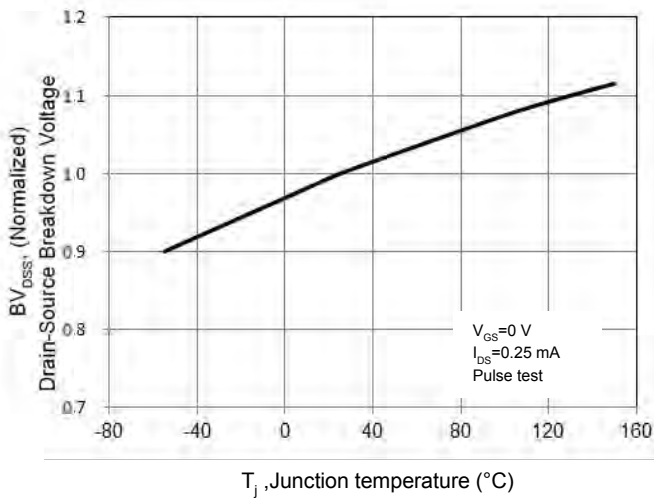


Figure 2. Transfer Characteristics

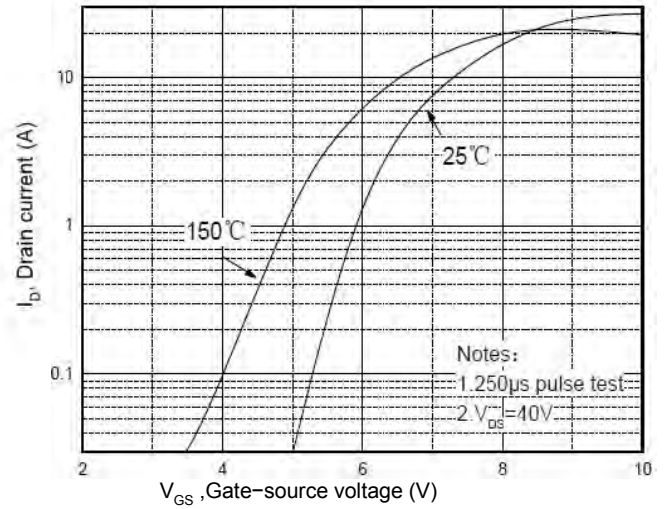


Figure 4. Threshold Voltage vs. Temperature

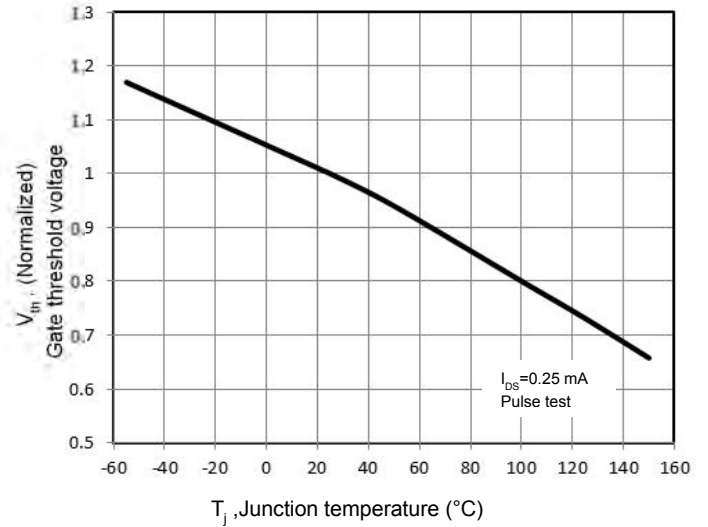


Figure 6. On-Resistance vs. Temperature

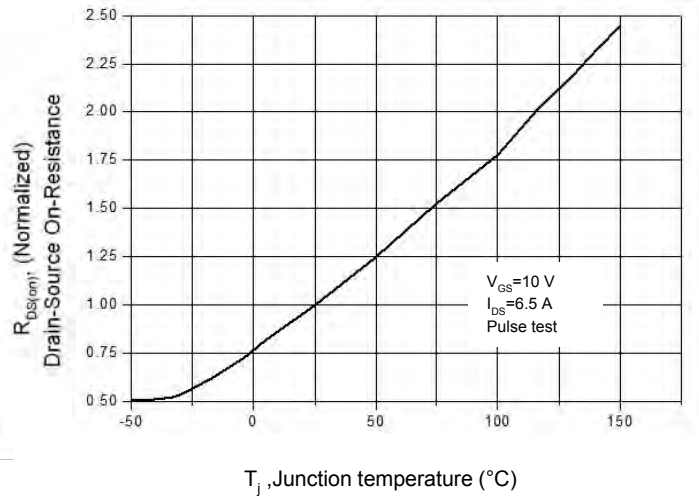


Figure 7. Capacitance Characteristics

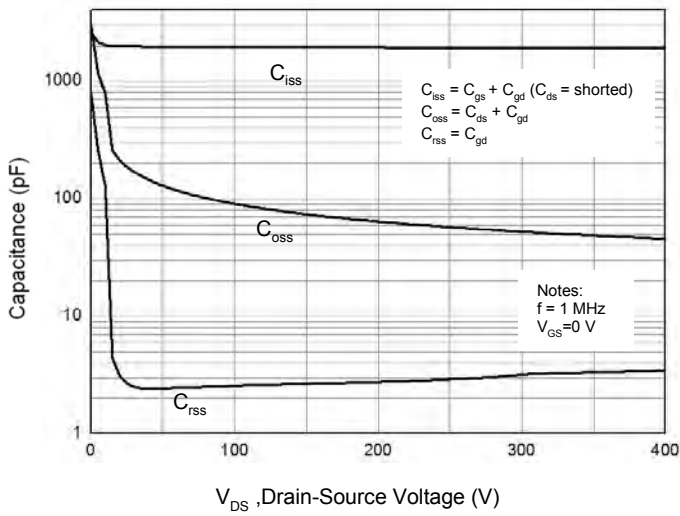


Figure 8. Gate Charge Characteristics

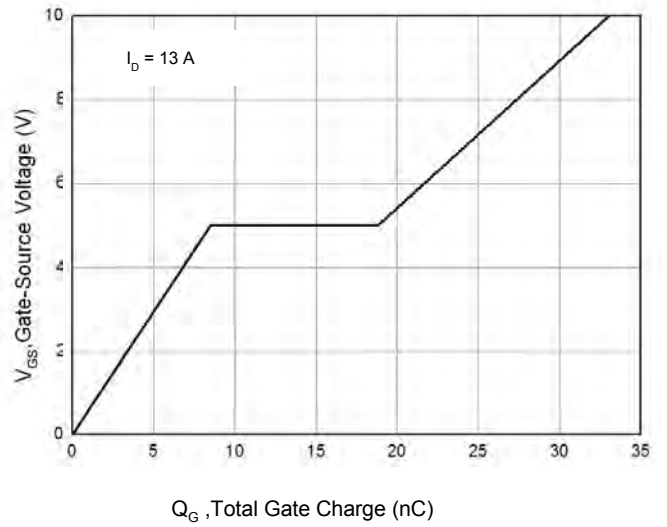


Figure 9. Maximum Safe Operating Area
TO-220F

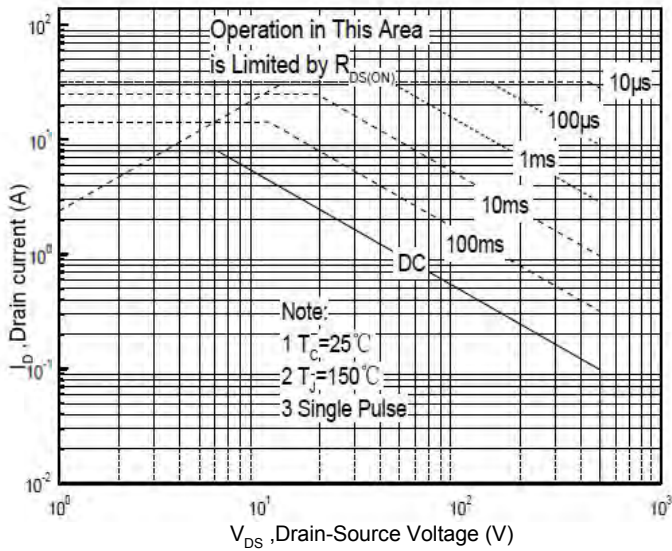


Figure 10. Maximum Safe Operating Area
TO-220

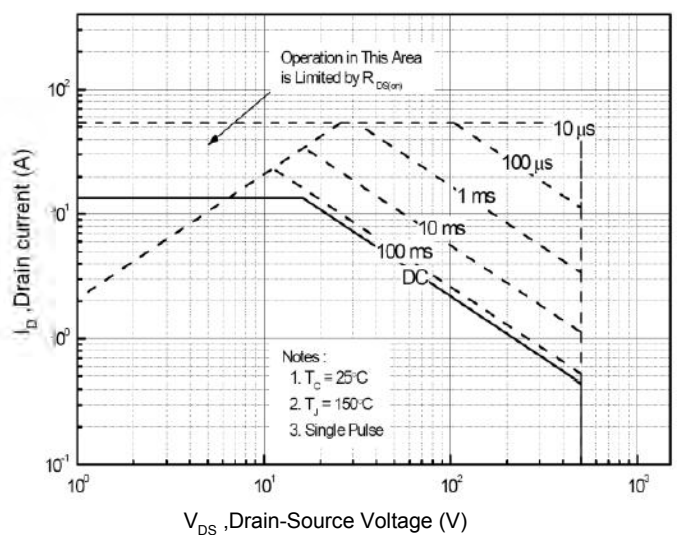


Figure 11. Power Dissipation vs. Temperature
TO-220F

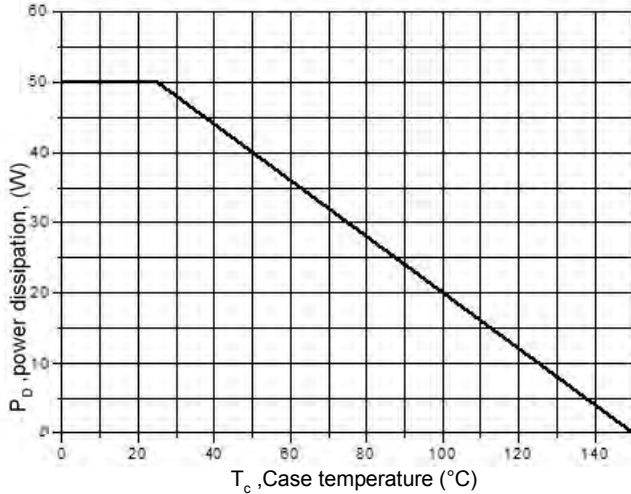


Figure 12. Power Dissipation vs. Temperature
TO-220

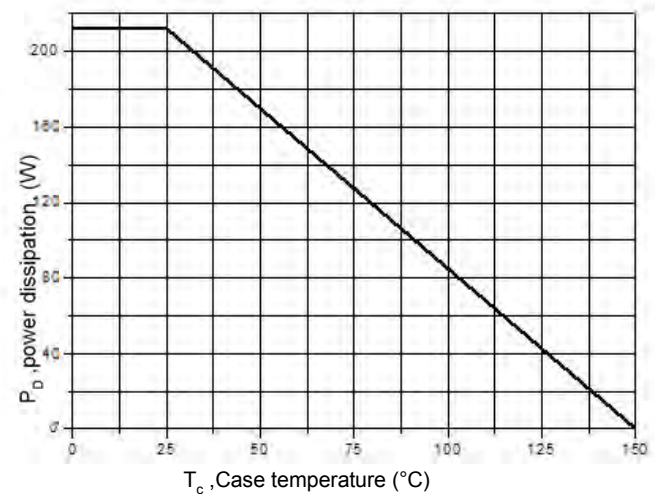
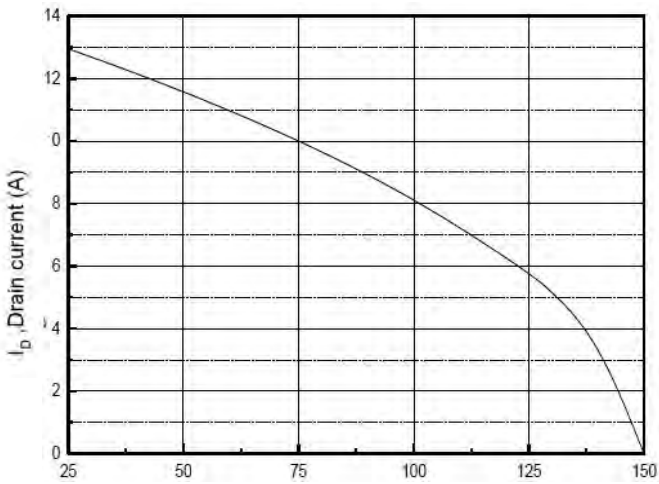


Figure 13. Continuous Drain Current vs. Temperature



T_c , Case temperature ($^{\circ}C$)

Figure 14. Body Diode Transfer Characteristics

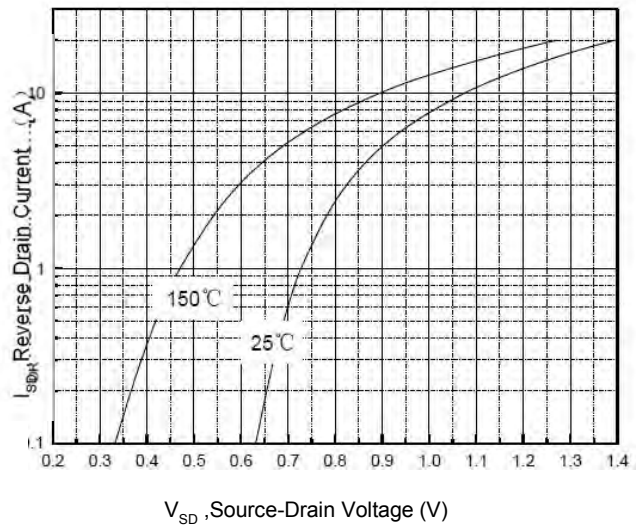


Figure 15 Transient Thermal Impedance, Junction to Case, TO-220F

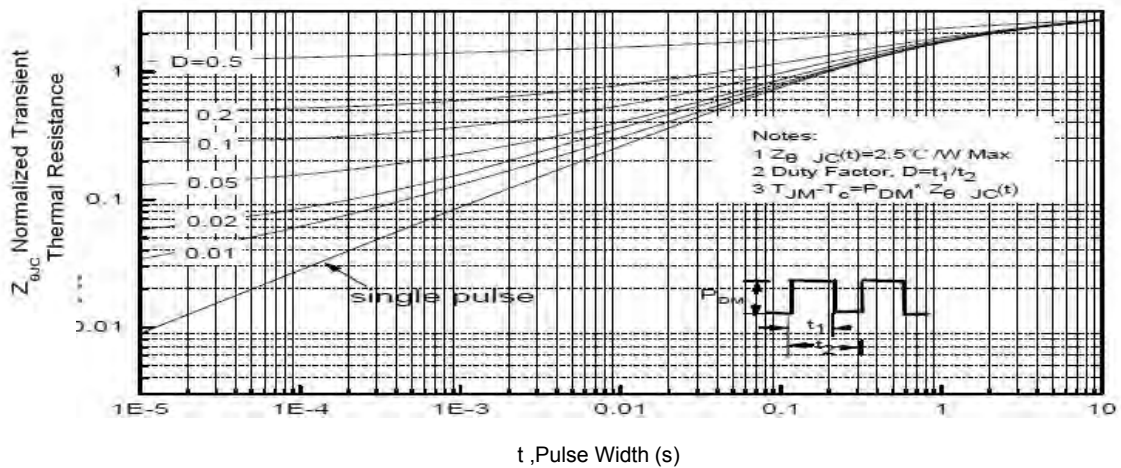
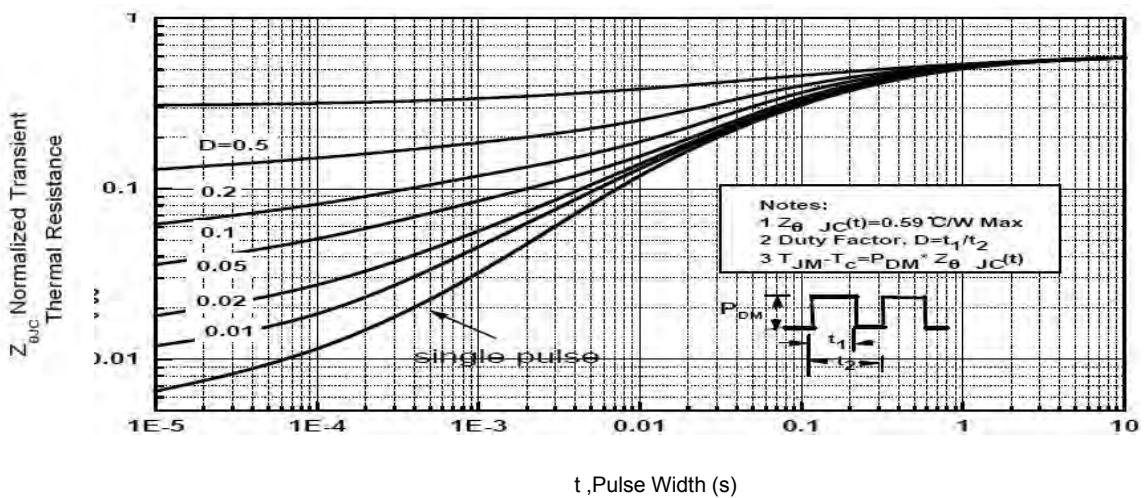
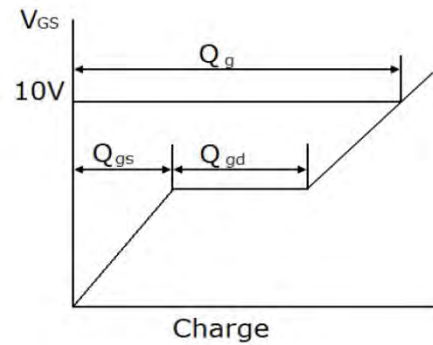
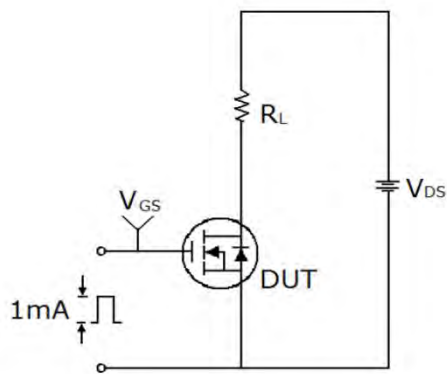


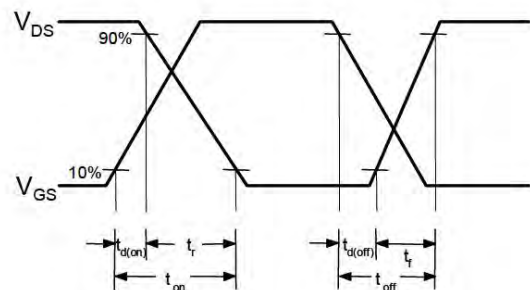
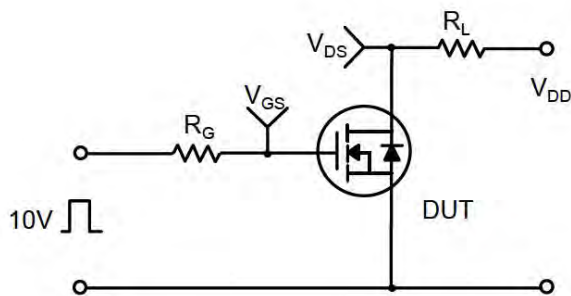
Figure 16. Transient Thermal Impedance, Junction to Case, TO-220



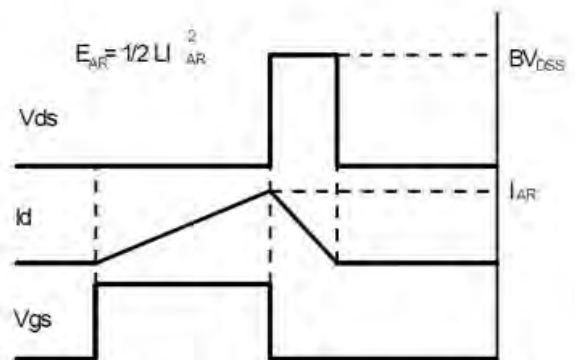
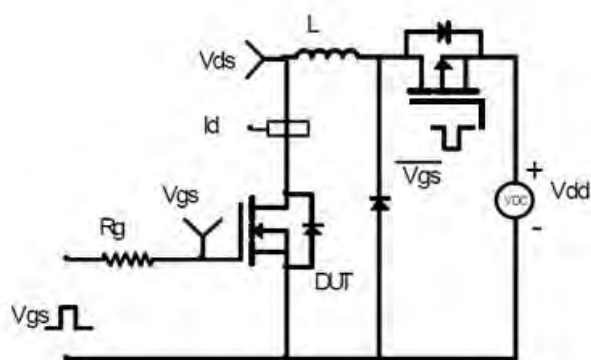
Gate Charge Test Circuit & Waveform



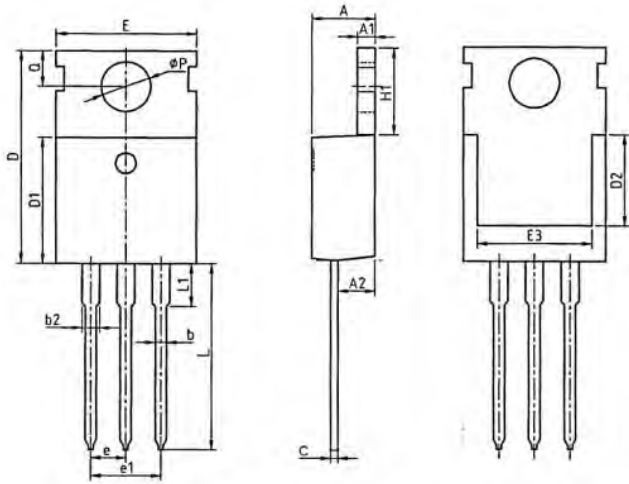
Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms

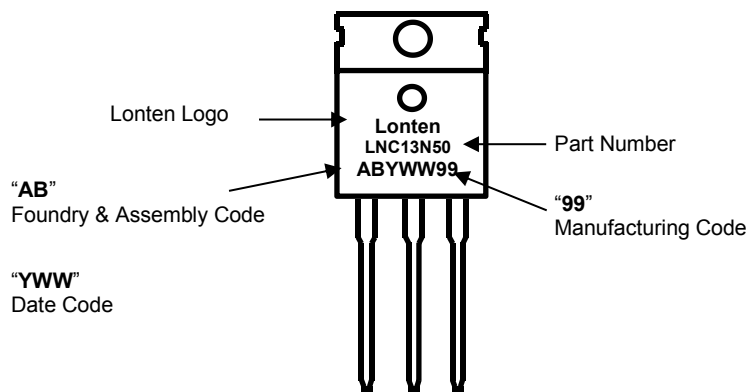


Mechanical Dimensions for TO-220

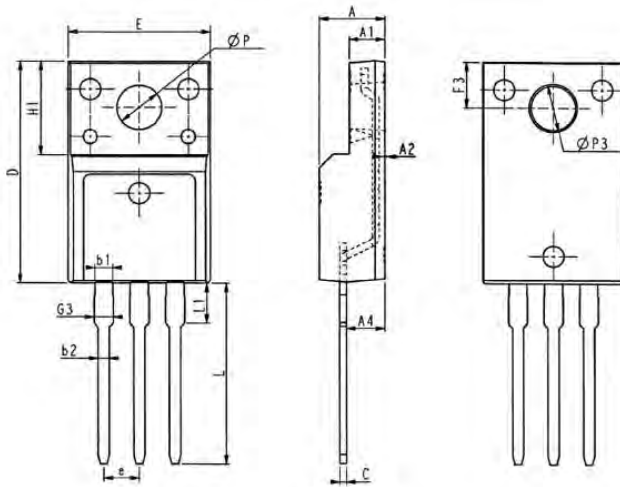


| COMMON DIMENSIONS | | | | | | |
|-------------------|---------|-------|-------|--------|-------|-------|
| SYMBOL | MM | | | INCH | | |
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 4.37 | 4.57 | 4.70 | 0.172 | 0.180 | 0.185 |
| A1 | 1.25 | 1.30 | 1.40 | 0.049 | 0.051 | 0.055 |
| A2 | 2.20 | 2.40 | 2.60 | 0.087 | 0.094 | 0.102 |
| b | 0.70 | 0.80 | 0.95 | 0.028 | 0.031 | 0.037 |
| b2 | 1.17 | 1.27 | 1.47 | 0.046 | 0.050 | 0.058 |
| c | 0.45 | 0.50 | 0.60 | 0.018 | 0.020 | 0.024 |
| D | 15.10 | 15.60 | 16.10 | 0.594 | 0.614 | 0.634 |
| D1 | 8.80 | 9.10 | 9.40 | 0.346 | 0.358 | 0.370 |
| D2 | 5.50 | — | — | 0.217 | — | — |
| E | 9.70 | 10.00 | 10.30 | 0.382 | 0.394 | 0.406 |
| E3 | 7.00 | — | — | 0.276 | — | — |
| e | 2.54BSC | | | 0.1BSC | | |
| e1 | 5.08BSC | | | 0.2BSC | | |
| H1 | 6.25 | 6.50 | 6.85 | 0.246 | 0.256 | 0.270 |
| L | 12.75 | 13.50 | 13.80 | 0.502 | 0.531 | 0.543 |
| L1 | — | 3.10 | 3.40 | — | 0.122 | 0.134 |
| øp | 3.40 | 3.60 | 3.80 | 0.134 | 0.142 | 0.150 |
| Q | 2.60 | 2.80 | 3.00 | 0.102 | 0.110 | 0.118 |

TO-220 Part Marking Information



Mechanical Dimensions for TO-220F



| COMMON DIMENSIONS | | | | | | |
|-------------------|---------|------|------|----------|------|------|
| SYMBOL | MM | | | INCH | | |
| | MIN | NOM | MAX | MIN | NO | MA |
| E | 9.96 | 10.1 | 10.3 | 0.39 | 0.40 | 0.40 |
| A | 4.50 | 4.70 | 4.90 | 0.17 | 0.18 | 0.19 |
| A1 | 2.34 | 2.54 | 2.74 | 0.09 | 0.10 | 0.10 |
| A2 | 0.30 | 0.45 | 0.60 | 0.01 | 0.00 | 0.02 |
| A4 | 2.65 | 2.76 | 2.96 | 0.10 | 0.10 | 0.11 |
| C | 0.40 | 0.50 | 0.38 | 0.01 | 0.02 | 0.02 |
| D | 15.57 | 15.8 | 16.1 | 0.61 | 0.62 | 0.63 |
| H1 | 6.70REF | | | 0.264REF | | |
| e | 2.54BSC | | | 0.1BSC | | |
| ØP | 3.03 | 3.18 | 3.38 | 0.11 | 0.12 | 0.13 |
| L | 12.68 | 12.9 | 13.2 | 0.49 | 0.51 | 0.52 |
| L1 | 2.88 | 3.03 | 3.18 | 0.11 | 0.11 | 0.12 |
| ØP3 | 3.15REF | | | 0.124REF | | |
| F3 | 3.15 | 3.30 | 3.45 | 0.12 | 0.13 | 0.13 |
| G3 | 1.25 | 1.35 | 1.55 | 0.04 | 0.05 | 0.06 |
| b1 | 1.18 | 1.28 | 1.43 | 0.04 | 0.05 | 0.05 |
| b2 | 0.70 | 0.80 | 0.95 | 0.02 | 0.03 | 0.03 |

TO-220MF Part Marking Information

